Small Signal MOSFET

-20 V, -223 mA, Single P-Channel, 0.62 x 0.62 x 0.4 mm XLLGA3 Package

Features

- Single P-Channel MOSFET
- Ultra Small and Thin Package (0.62 x 0.62 x 0.4 mm)
- Low R_{DS(on)} Solution in 0.62 x 0.62 mm Package
- 1.5 V Gate Voltage Rating
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Small Signal Load Switch
- Analog Switch
- High Speed Interfacing
- Optimized for Power Management in Ultra Portable Products

MAXIMUM RATINGS (T_J = 25°C unless otherwise stated)

Parameter		Symbol	Value	Units	
Drain-to-Source Voltage		V_{DSS}	-20	V	
Gate-to-Source Voltage		V_{GS}	±8.0	V	
Continuous Drain	Steady State	T _A = 25°C	I _D	-223	mA
Current (Note 1)	State	T _A = 85°C		-161	
	t ≤ 5 s	T _A = 25°C		-240	
Power Dissipation (Note 1)	Steady State	T _A = 25°C	P _D	121	mW
	t ≤ 5 s	T _A = 25°C		140	
Pulsed Drain Current $t_p = 10 \mu s$		I _{DM}	-669	mA	
Operating Junction and Storage Temperature		T _J , T _{STG}	-55 to 150	°C	
Source Current (Body Diode)		I _S	-121	mA	
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)		TL	260	°C	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Units
Junction-to-Ambient - Steady State (Note 1)	$R_{\theta JA}$	1035	°C/W
Junction-to-Ambient – t ≤ 5 s (Note 1)	$R_{\theta JA}$	895	

- Surface Mounted on FR4 Board using the minimum recommended pad size, (or 2 mm²), 1 oz Cu.
- 2. Pulse Test: pulse width \leq 300 μ s, duty cycle \leq 2%.

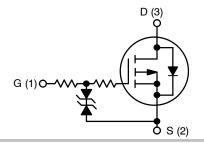


ON Semiconductor®

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MOSFET			
$V_{(BR)DSS}$	R _{DS(on)} MAX	I _D MAX	
	1.6 Ω @ -4.5 V		
-20 V	2.4 Ω @ -2.5 V	−223 mA	
	3.3 Ω @ –1.8 V	220 1171	
	4.5 Ω @ -1.5 V		

P-Channel MOSFET



MARKING DIAGRAM



XLLGA3 CASE 713AB



D = Specific Device Code

M = Date Code

ORDERING INFORMATION

Device	Package	Shipping [†]
NTNS3A91PZT5G	XLLGA3 (Pb-Free)	8000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Test Condition		Min	Тур	Max	Units
OFF CHARACTERISTICS		•		•			•
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$		-20			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J	I _D = -250 μA	A, ref to 25°C		11		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 \text{ V}, V_{DS} = -20 \text{ V}$	T _J = 25°C			-1.0	μΑ
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _{GS} = ±8.0 V				±2.0	μΑ
ON CHARACTERISTICS (Note 3)		•					
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}$	I _D = -250 μA	-0.4		-1.0	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J				2.1		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	$V_{GS} = -4.5 \text{ V},$	I _D = -100 mA		1.1	1.6	Ω
		V _{GS} = -2.5 V	′, I _D = −50 mA		1.5	2.4	
		V _{GS} = -1.8 V	∕, I _D = −20 mA		2.0	3.3	
		V _{GS} = -1.5 V	′, I _D = −10 mA		2.5	4.5	
Forward Transconductance	9FS	$V_{DS} = -5 \text{ V}, I_D = -100 \text{ mA}$			0.41		S
Source-Drain Diode Voltage	V_{SD}	$V_{GS} = 0 V$,	I _S = -10 mA		-0.6	-1.0	V
CHARGES & CAPACITANCES							
Input Capacitance	C _{ISS}	$V_{GS} = 0 \text{ V, f} = 10 \text{ kHz,}$ $V_{DS} = -15 \text{ V}$			41		pF
Output Capacitance	C _{OSS}				4.6		
Reverse Transfer Capacitance	C _{RSS}				4.1		
Total Gate Charge	Q _{G(TOT)}	$V_{GS} = -4.5 \text{ V}, V_{DS} = -15 \text{ V},$ $I_{D} = -200 \text{ mA}$			1.1		nC
Threshold Gate Charge	Q _{G(TH)}				0.1		
Gate-to-Source Charge	Q_{GS}				0.2]
Gate-to-Drain Charge	Q_{GD}				0.23		
SWITCHING CHARACTERISTICS, VG	S = 4.5 V (Note 3)						
Turn-On Delay Time	t _{d(ON)}	V_{GS} = -4.5 V, V_{DD} = -15 V, I_{D} = -200 mA, R_{G} = 2 Ω			41		ns
Rise Time	t _r				97		
Turn-Off Delay Time	t _{d(OFF)}				571		
Fall Time	t _f				286		

^{3.} Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS

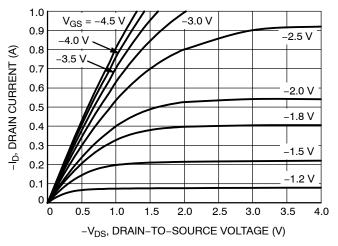


Figure 1. On-Region Characteristics

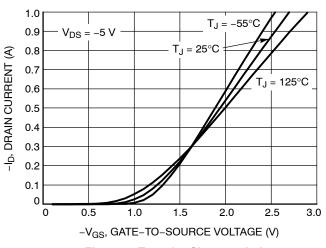


Figure 2. Transfer Characteristics

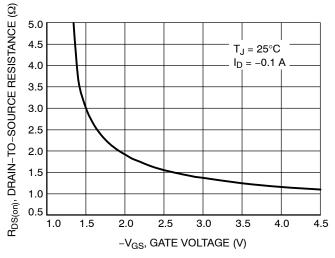


Figure 3. On-Resistance vs. Gate-to-Source Voltage

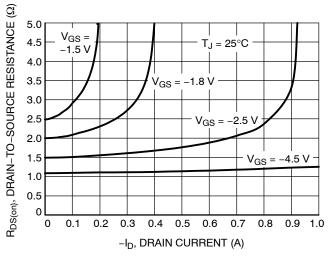


Figure 4. On-Resistance vs. Drain Current and Gate Voltage

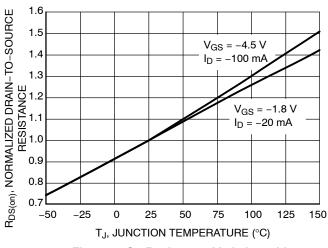


Figure 5. On Resistance Variation with Temperature

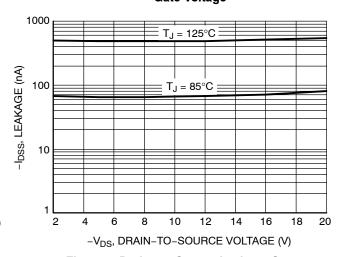
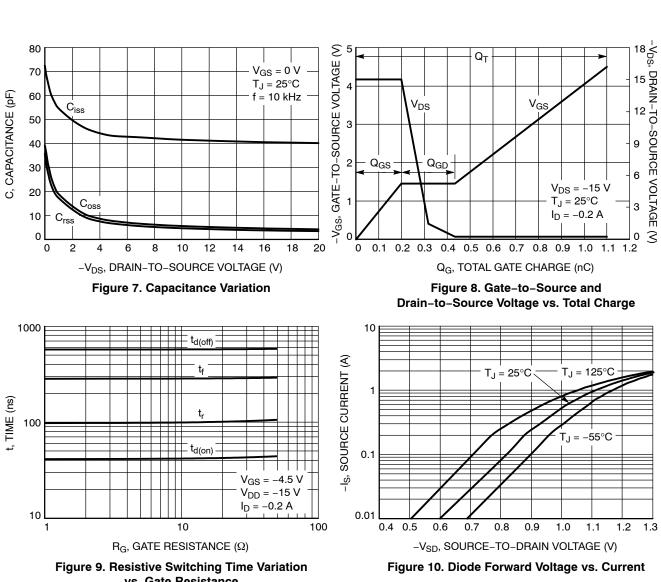


Figure 6. Drain-to-Source Leakage Current vs. Voltage

TYPICAL CHARACTERISTICS



vs. Gate Resistance

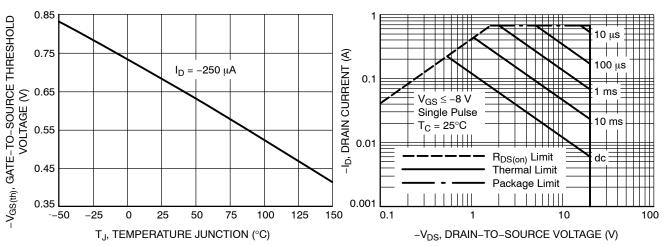


Figure 11. Threshold Voltage

Figure 12. Maximum Rated Forward Biased Safe Operating Area

TYPICAL CHARACTERISTICS

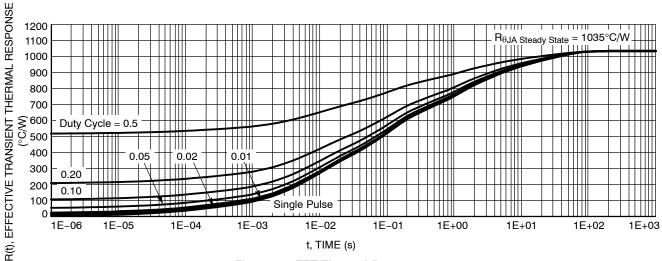
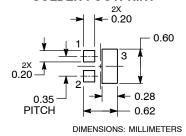


Figure 13. FET Thermal Response

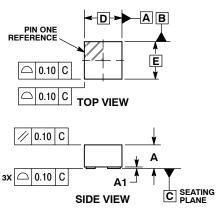
MINIMUM RECOMMENDED SOLDER FOOTPRINT*



^{*}Dependent upon end user capabilities, this footprint could be used as a minimum.

PACKAGE DIMENSIONS

XLLGA3, 0.62x0.62, 0.35P CASE 713AB **ISSUE O**

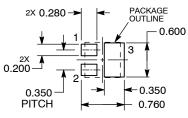


NOTES:

- 1. DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994
- CONTROLLING DIMENSION: MILLIMETERS.

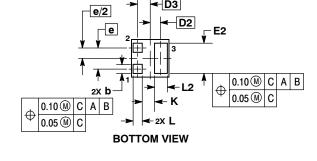
001111102210 2			
	MILLIMETERS		
DIM	MIN	MAX	
Α	0.340	0.440	
A1	0.000	0.030	
b	0.100	0.200	
D	0.620 BSC		
D2	0.175 BSC		
D3	0.205 BSC		
Е	0.620 BSC		
E2	0.400	0.600	
е	0.350 BSC		
K	0.200 REF		
L	0.090	0.210	
L2	0.110	0.310	

RECOMMENDED SOLDER FOOTPRINT*



DIMENSIONS: MILLIMETERS

*Additional information concerning board mounting for this package may be found in Document AND9099/D, "Board Level Application Note for XLLGA 3-Lead 0.62x0.62 Package". For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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